NSN 5962-01-480-6527

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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
C141 awcfs gp
Features Provided:
Ultraviolet erasable and monolithic
Inclosure Configuration:
Dual-in-line
Output Logic Form: Complementary metal evide comisenduater logic
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input Product Name:
Microcircuit, digital, memory, cmos, uv erasable-programming logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
20.00 nanoseconds af output megawatts
Memory Device Type:
Pal Pal
Special Features:
This item shall be made from an unprogrammed device which is in accorance with smd specifications 5962-8872404lx
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0